Supporting Information

Non-Adiabatic Reaction Dynamics in the Gas-Phase Formation of Phosphinidenesilylene (HPSi) – The Isovalent Counterpart of Hydrogen Isocyanide (HNC) - Under Single-Collision Conditions

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1. Experimental and Computational

Experimental: The gas-phase reaction of atomic silicon (Si; ${}^{3}P$) with phosphine (PH₃; X¹A₁) was studied under single-collision conditions using a universal crossed molecular beams machine at the University of Hawaii.¹ In the primary source chamber, a pulsed supersonic beam of ground state silicon atoms was prepared *in situ* by ablation of silicon from a rotating silicon rod at 266 nm (Nd:YAG laser; 5 ± 1 mJ per pulse; 30Hz)² and seeding the ablated atoms in neon gas (Ne; 99.999%; Specialty Gases of America). The neon-seeded beam of silicon atoms was skimmed and velocity-selected by a four-slot chopper wheel yielding a peak velocity v_p of 947 \pm 17 m s⁻¹ and speed ratio S of 6.8 ± 0.4 (Table S1). Laser-induced fluorescence interrogation of neon-seeded silicon beam indicates that all silicon atoms are in their electronic ground state (^{3}P) .³ In the secondary source chamber, the supersonic beam of phosphine (\geq 99.9995%; Matheson Tri-Gas), which was regulated at 550 Torr with $v_p = 805 \pm 9$ m s⁻¹ and S = 12.4 ± 0.1 (Table S1), crossed perpendicularly with the primary beam silicon atoms in the main chamber leading to a collision energy ($E_{\rm C}$) of (11.9 ± 0.2) kJ mol⁻¹ and a center of mass angle ($\Theta_{\rm CM}$) of $(45.9 \pm 0.5)^{\circ}$. The neutral reaction products entering the detector were ionized by electron impact ionizer (80 eV),⁴ then filtered according to the mass-to-charge ratio (m/z) utilizing a quadrupole mass spectrometer (QMS, Extrel, QC 150), and eventually recorded by a Daly-type ion counter.⁵ The detector is housed within a triply differentially pumped and rotatable chamber that allows the collection of angularly-resolved time-of-flight (TOF) spectra in the plane defined by both reactant beams. To obtain the information on the reaction dynamics, a forward-convolution method was used to transform the laboratory frame (LAB) data into the center of mass frame (CM),⁶⁻⁷ which represents an iterative method whereby user-defined CM translational energy $P(E_T)$ and angular $T(\theta)$ flux distributions are varied iteratively until a best fit of the laboratoryframe TOF spectra and angular distributions are achieved. These functions comprise the reactive differential cross-section $I(\theta, u)$, which is taken to be separable into its CM scattering angle θ and CM velocity u components, $I(u, \theta) \sim P(u) \times T(\theta)$. The error ranges of the $P(E_T)$ and $T(\theta)$ functions are determined within the 1σ limits of the corresponding laboratory angular distribution and beam parameters (beam spreads, beam velocities) while maintaining a good fit of the laboratory TOF spectra.

Computational:

The electronic structure calculations reported in this work were performed using the GAMESS-US⁸ and MOLPRO⁹ packages. First, density functional theory (DFT)¹⁰ calculations employing the M06-2X¹¹ exchange and correlation functional were used along with the cc-pV(T+d)Z basis set¹²⁻¹⁴. Note that the functional chosen is documented to perform better than conventional and widely used ones for barrier heights (both hydrogen-transfer and non-hydrogen-transfer), with mean errors around 5 kJ mol⁻¹.¹⁵ For the specific chemical elements explored in this work, such calculations for the P-H and Si-H bond energy in PH₃ and SiH₄ agree with the experimental values¹⁶⁻¹⁷ within 8 and 9 kJ mol⁻¹ (respectively). All calculations employ restricted wavefunctions in order to avoid spin contamination. Vibrational analyses were carried out for all stationary points found within the M06-2X/cc-pV(T+d)Z approach. Structures that corresponded to energy minima were confirmed by presenting only real vibrational frequencies, while transition states (TSs) were confirmed by the presence of a single imaginary frequency. Intrinsic reaction coordinate (IRC) calculations starting from each TS were performed to ensure the correct connection paths. The reported energies of all structures are always zero-point energy (ZPE) corrected and no symmetry restrictions were imposed in any calculation.

Singlet/triplet crossings

A search for the lowest energy on the seam of intersections between singlet and triplet electronic potential energy surfaces was also carried out with the M06-2X/cc-pV(T+d)Z method without any constraints and yielded two different minimum energy crossing points (MSXs). The MSXs are not conventional stationary structures on the potential energy surface, and to perform ZPE corrections for these cases, a different procedure is performed. First, we calculate the conventional Hessian matrix for both singlet and triplet states independently at the MSX geometry. After that, the coordinate perpendicular to the seam must be projected out (along with the rotational and translational degrees of freedom) to generate a new effective Hessian matrix as described in Refs.¹⁸⁻²⁰. The new effective Hessian matrix is then diagonalized to provide the 3N–7 vibrational frequencies of the MSX, using the implementation described in Ref.²¹. These final frequencies are used for ZPE corrections of the MSX energies.

The probabilities of singlet-triplet transitions depend on the magnitude of the spin-orbit coupling (SOC). To calculate this, we have used the full valence complete active space self-consistent

field (CASSCF) method with the aug-cc-pV(Q+d)Z basis set. After reoptimization of the crossing point, the full spin-orbit matrix was calculated with the Breit-Pauli operator²² as implemented in MOLPRO. The spin-free electronic Hamiltonian eigenstates, |S>, |T, 1>, |T, 0>, and |T, -1>, are employed to build the total Hamiltonian matrix representation (H_{el} + H_{SO}). The magnitude of the V_{SO} term is then calculated from the matrix elements as:

$$V_{SO}^2 = \sum_{M_S=-1}^{1} |\langle T, M_S | H_{SO} | S \rangle|^2.$$

Energy refinement and multireference character

To further improve the accuracy of our results, we have performed single point energy calculations at the CCSD(T)-F12/aug-cc-pV(T+d)Z²³⁻²⁴ level in all geometries optimized at the M06-2X/cc-pV(T+d)Z level, and we report these energies in the manuscript, which are abbreviated as CCSD(T)-F12/aug-cc-pV(T+d)Z//M06-2X/cc-pV(T+d)Z+ZPE(M06-2X/cc-pV(T+d)Z). From the CCSD(T)-F12 calculations, we could also extract the T1²⁵ diagnostic to check if some of the reported structures had a higher than usual multireference (MR) character. The values are given in Table S3, from where it can be seen that most structures show T1<0.03, for which cases the MR character should not be a serious problem. The exceptions are **p4**, the transition states from **T**_{2a} to **p3**, and **T**_{2a} to **p4** (both of which are too high in energy to be relevant for the experimental conditions), and from **S**₂ to **p2**, and **S**₂ to **S**₃.

To address the possibility of an inaccurate result caused by MR character, we tackle the problem in two ways. First, we repeated all the geometry optimizations and frequency calculations using a DFT functional with better performance for MR structures (and less HF exchange), for which case we choose the M06 functional, which is known to perform about 2.4 times better¹⁰ than M06-2X for systems with a strong MR character. The results are given in Figure S2, in which the values for both M06-2X and M06 are given together. As can be seen, both functionals have an overall good agreement regarding the possible reaction mechanisms, and their deviations in cases with a larger T1 diagnostic is within the expected accuracy of a DFT calculation.

Secondly, for the cases with a larger T_1 diagnostic with possible consequences for the interpretation of the experiments, we have performed accurate multi-reference calculations to make sure all the conclusions are correct. Their geometry were first optimized at the full valence

CASSCF level with the aug-cc-pV(Q+d)Z basis set, followed by a ZPE calculation. At the optimized geometries we have refined the energy values by performing a multireference configuration interaction calculation including the Davidson correction, MRCI(Q), also with the aug-cc-pV(Q+d)Z basis set. The energy of the transition states from S₂ to **p2** and from S₂ to S₃, are relevant to the final product distribution and have significant MR character, and we therefore compare the M06-2X, M06, CCSD(T)-F12 and MRCI(Q) results (calculated as described above). As the relevant parameter for the RRKM calculations is the energy difference between the TS and the S₂ minimum, we report below the energies with respect to S₂ in kJ mol⁻¹.

	MRCI(Q)	CCSD(T)-F12	M06-2X	M06
S ₂ -S ₃	103	111	114	104
S ₂ -p2	180	193	183	180

Considering that the MRCI energy is not exact and still may show a 4 kJmol⁻¹ error, the results are in a fairly good agreement, in spite of the T₁ diagnostic, and therefore we believe that the interpretation of the experiments throughout the manuscript is correct.

Finally, the T1 diagnostic of the triplet state of the HPSi molecule (p4) was 0.034, and it can be seen from Figure S2 that the M06 functional predicts that triplet HSiP (p3) is slightly lower than p4, while M06-2X predicts them as nearly degenerate. Even though this product was not observed experimentally in this work, it is worth predicting an accurate value for its energy at the MRCI(Q) level. With this, we found that HSiP is indeed 15 kJ mol⁻¹ lower in energy than HPSi, which agrees well with the difference of 19 kJ mol⁻¹ at the CCSD(T)-F12 level reported in the Figure 3 of the manuscript.



Figure S1. Schematic representation of reactants and products of the reaction of atomic silicon (Si; ${}^{3}P/{}^{1}D$) with phosphine (PH₃; X¹A₁) leading to **p1 - p8**. Energies calculated at the CCSD(T)-F12/aug-cc-pV(T+d)Z//M06-2X/cc-pV(T+d)Z+ZPE(M06-2X/cc-pV(T+d)Z) level are shown in kJ mol⁻¹ and are relative to the energy of the separated reactants. Atoms are colored as follows: silicon (purple); hydrogen (gray); phosphorus (pink).



Figure S2. Schematic representation of the potential energy surface of the reaction of atomic silicon (Si; ${}^{3}P/{}^{1}D$) with phosphine (PH₃; X¹A₁). The plain numbers give the energies at the M06-2X/cc-pV(T+d)Z level, and those under parenthesis refer to M06/cc-pV(T+d)Z calculations. All results are zero-point energy corrected. The asterisk indicates that, although the T_{2c}-T_{2b} TS seem degenerate with the T_{2c} minimum at the M06 level, the ZPE uncorrected energy shows a true TS slightly above T_{2c} with a single imaginary frequency. Atoms are colored as follows: silicon (purple); hydrogen (gray); phosphorus (pink).

Beam	v_p (m s ⁻¹)	S	$E_{\rm C}$ (kJ mol ⁻¹)	Θ _{CM} (degree)
Si(³ P)	947 ± 17	6.8 ± 0.4		
$PH_{3}(X^{1}A_{1})$	805 ± 9	12.4 ± 0.1	11.9 ± 0.2	45.9 ± 0.5

Table S1. Peak velocities (v_p) and speed ratios (S) of the silicon (Si), and phosphine (PH₃) beams along with the corresponding collision energy (E_C) and center-of-mass angle (Θ_{CM}).

Table S2. Statistical branching ratios (%) for the reaction of the silicon atom (Si; ³P) with phosphine (PH₃; X¹A₁). Here, **p1** and **p2** denote singlet phosphinidenesilylene (HPSi; X¹A') and singlet silylidynephosphine (HSiP; X¹ Σ ⁺), respectively.

$E_{\rm C}$ (kJ mol ⁻¹)	$S_2 \rightarrow p1$	$S_3 \rightarrow p1$	$S_2 \rightarrow p2$	$S_3 \rightarrow p2$
0	62.29	11.86	25.84	0.01
11.9	53.39	13.11	33.46	0.04

Table S3. Optimized Cartesian coordinates and vibrational frequencies for all intermediates, transition states, minima-on-the-seam-of-crossings (MSX), reactants, and products involved in the reactions of the atomic silicon (Si; ${}^{3}P/{}^{1}D$) with phosphine (PH₃; X¹A₁).

Reagents

PH3; C3V; X1A1

Р	0.0657489556	-0.0000001858	-0.0019137497
Н	-0.7320439127	0.0000003515	1.1624302654
Н	-0.6826538144	1.0274840772	-0.6156228017
Н	-0.6826536606	-1.0274842429	-0.6156233055

Frequencies

1020.828 1156.119 1156.576 2457.598 2460.576 2462.354

T1 diagnostic: 0.01428312

Products

 H_2

Н	0.0000000000	0.0000000000	0.3694968462
Н	0.0000000000	0.0000000000	-0.3694968462

Frequencies

4464.920

T1 diagnostic: 0.00594717

HPSi – triplet; C_s; ³A"

Р	0.0000000000	-0.0488355711	-1.0502786731
Si	0.0000000000	0.0053951945	1.2049906034
Н	0.0000000000	1.3503725664	-1.3013513088

445.27 686.35 2368.55

T1 diagnostic: 0.03382185

HSiP – triplet; C_s ; ³A'

Si	0.0000000000	-0.0630418847	-1.0618623751
Р	0.0000000000	0.0156022102	1.0204344861
Н	0.0000000000	1.2442727099	-1.7971643838

Frequencies

552.801 620.114 2123.135

T1 diagnostic: 0.02753003

HSiP – singlet; $C_{\infty v}$; ¹ Σ^+

Si	0.0000000000	0.0000000000	-0.9730704991
Р	0.0000000000	0.0000000000	0.9630601956
Н	0.0000000000	0.0000000000	-2.4454507659

Frequencies

330.88 331.03 778.15 2296.63

T1 diagnostic: 0.02204396

HPSi – singlet; C_s; ¹A'

Si 0.000000000	0.0180207923	-1.0744441180
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Н	0.0000000000	-1.2593728551	0.2117421948
Р	0.0000000000	0.0262746117	0.9665566538

673.503 885.731 2013.335

T1 diagnostic: 0.01911852

c-HSiPH

Si	-0.0002891442	0.0599311195	-1.0656052695
Н	0.0003978713	-1.1644669015	-1.9165046913
Р	-0.0002405733	0.0247875833	1.0033437233
Н	0.0001236412	-1.3900810571	0.8534957485

Frequencies

443.110 496.689 620.344 728.547 2172.667 2384.890

T1 diagnostic: 0.02293153

 SiPH_2

Р	-0.007083245	-7.651E-07	-0.952459448
Si	-0.007026817	1.0829E-06	1.206108617
Η	0.611984756	1.088345885	-1.586755959
Η	0.611984896	-1.088346175	-1.586758372

Frequencies

85.664 516.442 519.684 1099.794 2476.686 2489.275

T1 diagnostic: 0.02201284

t-HSiPH

Si	-0.001121064	0.059656434	-1.051034566
Н	0.000054053	-1.201548382	-1.845544528
Р	0.001550997	-0.0698775	1.006678943
Н	-0.000432688	1.336709242	1.167899985

Frequencies

486.108 517.489 618.941 799.884 2184.361 2425.324

T1 diagnostic: 0.02926840

H2SiP

Si	-4.53118E-05	3.2107E-06	-1.016439058
Р	0.000308946	-4.0339E-06	1.034078961
Н	-0.00018872	1.218996045	-1.847328757
Н	-0.000188757	-1.218995172	-1.847321565

Frequencies

470.927
532.046
637.480
951.198
2270.951
2289.755

Intermediates

S₁: SiPH₃; C_s; ¹A'

Р	-0.0319137525	0.1448434866	-1.0514660901
Si	-0.1013182048	-0.2617615912	1.1358582412
Н	-1.0653967923	0.5710264446	-1.9254211011
Н	1.0453655690	0.6080548866	-1.8505414284
Н	0.0032659206	-1.2305106665	-1.3525451615

Frequencies

307.059 440.759 518.405 904.242 991.556 1215.366 2315.492 2377.155 2481.575

T1 diagnostic: 0.01903879

T₁: SiPH₃; C_s; ³A"

Р	-0.0165255199	-0.0000079012	-1.0183490506
Si	0.0097643708	0.0000033416	1.2767392804
Н	1.2019260084	0.0000082112	-1.7266374244
Η	-0.6374209112	-1.0624130355	-1.7054938117
Н	-0.6374092854	1.0624093840	-1.7054896972

Frequencies

349.796 433.897 436.340 1045.821 1112.464 1112.654 2438.551 2438.729 2449.768 T1 diagnostic: 0.01728985

T_{2c}: HSiPH2;

Р	-1.0176895655	0.0454924199	-0.0001767107
Si	1.2801854915	0.0238966169	-0.0004684907
Η	-1.6414381375	-0.6419281666	1.0610148565
Η	-1.6417060079	-0.6480900352	-1.0572071985
Η	0.5583340894	-1.3725813751	0.0037738833

Frequencies

 $\begin{array}{c} 214.388\\ 371.165\\ 416.352\\ 594.096\\ 719.400\\ 1100.885\\ 1793.358\\ 2435.502\\ 2446.735\end{array}$

T1 diagnostic: 0.02677059

T_{2b}: HSiPH₂; C_s; ³A"

Si	-0.0677196653	-0.1126810737	-1.1842206615
Р	-0.0254978580	0.0692834278	1.0473488382
Н	1.3269181877	-0.3155169764	1.1919507665
Н	0.9866172567	0.4616067166	-2.0543963752
Н	0.2598596790	1.4535738557	1.0694854520

Frequencies

 $\begin{array}{c} 213.864\\ 447.391\\ 504.125\\ 683.444\\ 726.257\\ 1110.483\\ 2209.441\\ 2428.843\\ 2432.091 \end{array}$

T1 diagnostic: 0.01993677

T_{2a}: HSiPH₂; C_s; ³A"

Р	-0.0731841655	0.0002958151	-1.0437309182
Si	0.0666272805	-0.0003694353	1.1815660841
Н	0.8490097075	1.0346233839	-1.3118941627
Н	0.8474235771	-1.0353230377	-1.3123810336
Н	-1.2356882694	0.0004292093	1.8876247257

Frequencies

234.933 450.841 525.444 677.358 729.121 1123.347 2222.398 2442.862 2445.477

T1 diagnostic: 0.02684615

S₂: HSiPH₂; C₁; ¹A

Р	-0.0611302598	-0.0022466922	-1.0210012220
Si	0.0230950033	0.0508314562	1.1814841787
Н	0.6157392084	1.1297506545	-1.4984142360
Н	0.7609067573	-1.0236709519	-1.5202845471
Н	-0.0376407214	-1.4595427092	1.1860358819

Frequencies

 $\begin{array}{c} 209.076\\ 488.062\\ 513.009\\ 519.667\\ 818.151\\ 1107.689\\ 2099.036\\ 2491.272 \end{array}$

2510.576

T1 diagnostic: 0.02064757

T_{3b}: H₂SiPH; C_s; ³A"

Si	0.0025982593	0.0005696574	-1.1600188502
Р	-0.0305882913	-0.0008887138	1.0879954593
Η	-0.6508317715	1.2063303851	-1.7202077210
Η	-0.6453498246	-1.2074519571	-1.7217125067
Η	-1.4486100918	-0.0043534916	1.1266611385

Frequencies

330.008 452.898 497.122 504.744 746.937 914.577 2221.540 2246.035 2400.879

T1 diagnostic: 0.01737763

T_{3a}: H₂SiPH; C_s; ³A"

Si	0.0532368543	-0.0330639038	-1.1498781380
Р	-0.0527187511	0.0093103118	1.0941414970
Н	-1.1189797476	-0.7564148381	-1.6969807562
Н	0.0200355775	1.3495336165	-1.6828838274
Н	1.1788111193	-0.6597644851	1.2865216373

Frequencies

273.475 453.755 527.275 554.559 746.773 927.669 2221.255 2241.750 2424.889

T1 diagnostic: 0.02023070

S₃: H₂SiPH; C_s; ¹A'

Si	-0.0004061624	-0.0006313767	-1.0335912507
Р	-0.0011280030	0.0447444991	1.0224291721
Н	-0.0011869734	1.2238955015	-1.8522254331
Н	0.0008003725	-1.2083840326	-1.8778493892
Η	0.0001479545	-1.3725789235	1.0204239941

Frequencies

471.271 540.246 619.442 630.834 758.777 972.929 2284.226 2307.183 2420.222

T1 diagnostic: 0.01789945

T₄: H₃SiP; C_s; ³A"

Si	0.0022993848	0.000002809	-1.0949847963
Р	-0.0067987780	-0.0000003970	1.1480136847
Н	1.3933100351	-0.0000001075	-1.5939684279
Н	-0.6896908391	-1.2029612801	-1.6032729693
Н	-0.6896910941	1.2029615037	-1.6032737686

Frequencies

459.281 505.540 505.663 909.236 950.620 950.818 2260.417 2267.789 2267.917

T1 diagnostic: 0.01351617

Transition states

 T_1 - HPSi

Р	-0.6408224232	0.1096626883	-0.8801031204
Si	0.2215050556	-0.1950568580	1.2644639802
Н	0.7992402822	0.3248791818	-1.4946643314
Н	-0.5615448008	-1.0708032896	-1.6560710735
Н	0.1817042527	0.8307306117	-2.0109084228

Frequencies

-1274.405 168.716 350.855 437.966 933.090 1078.274 1779.341 2152.651 2404.554

T1 diagnostic: 0.02197400

 S_1 - HPSi

Р	0.0172259844	-0.0624066249	-0.9050676372
Si	-0.0099881102	0.0134348811	1.2075147596
Н	0.5482766727	1.0949620991	-1.7903234554
Н	0.0589225704	-0.9059752884	-2.0284611778
Н	-0.5079397383	1.0787819497	-1.8152346708

-1516.106 72.037 395.410 528.344 951.764 1167.122 1743.381 1957.749 2437.445

T1 diagnostic: 0.02341995

T₁ - T₂

Р	0.0135894813	0.0007288556	-1.1000971427
Si	0.0473650644	-0.0013928628	1.4571309106
Η	-0.4622831724	1.0603258865	-1.8982482196
Η	-0.4572824446	-1.0602658539	-1.8993780766
Н	-1.1845791378	-0.0025482822	-0.2864676479

Frequencies

-498.878 198.018 267.153 989.052 1025.160 1125.663 2148.721 2450.122 2460.897

T1 diagnostic: 0.02039706

S₁ - S₂

Р	-0.0354393643	0.1770926466	-1.0212779418
Si	-0.1025024120	-0.2794754928	1.0811259648
Н	-1.0896230559	0.4498022001	-1.9375122683
Н	1.0151796251	0.2050889941	-1.9792578463
Н	0.2026597272	-1.2239863899	-0.7032858584

-717.054 446.533 542.704 567.439 1091.866 1239.970 2149.222 2294.277 2347.895

T1 diagnostic: 0.02335835

 T_1 - T_{2c}

Р	0.0135894813	0.0007288556	-1.1000971427
Si	0.0473650644	-0.0013928628	1.4571309106
Н	-0.4622831724	1.0603258865	-1.8982482196
Н	-0.4572824446	-1.0602658539	-1.8993780766
Н	-1.1845791378	-0.0025482822	-0.2864676479

Frequencies

-498.878 198.018 267.153 989.052 1025.160 1125.663 2148.721 2450.122 2460.897

T1 diagnostic: 0.02039706

 $T_{2c}-T_{2b} \\$

Р	-1.1642105984	0.0825129775	-0.0007357653
Si	1.2598979478	-0.1526403032	-0.3197909676
Η	-1.7253381877	-0.9107393651	0.8260214594
Н	-1.8883978389	-0.3063452097	-1.1497406961

Η

Frequencies

-900.460
197.817
266.050
455.423
473.141
1124.405
2023.588
2429.315
2467.545

T1 diagnostic: 0.02872943

 T_{2a} - T_{2b}

Р	0.0028989478	-0.4707063954	-1.4707362878
Si	0.1004855332	-0.6183794650	0.7848760314
Н	-1.3836081778	-0.2024943127	-1.5328639465
Η	0.3420289825	0.9027022432	-1.4272998604
Η	1.0185797668	0.2984786313	1.4969444760

Frequencies

-253.278 439.984 511.355 640.877 749.793 1089.927 2229.197 2426.167 2433.875

T1 diagnostic: 0.02211549

T_{2a} - HPSi

Р	-0.0001607814	-0.0067063495	-0.9915415515
Si	-0.0003129447	-0.0411138413	1.1528737468
Н	-0.4000175078	1.7077467911	-1.6523653755

Η	0.3996103564	1.7076763547	-1.6526331836
Η	-0.0006108175	-1.4151090027	0.3748794609

-902.132
222.177
314.549
517.134
624.739
771.411
1032.008
1816.478
3484.438

T1 diagnostic: 0.04505358

T_{2a} - HSiP

Р	-0.1284437991	0.0077950100	-1.0363960831
Si	0.0394655614	0.0448164674	1.0856929665
Н	1.6326753762	0.2991827383	-1.4558543588
Н	1.6168586273	-0.5013987640	-1.3494033143
Н	-0.1420806977	-1.2163312098	1.8665088742

Frequencies

 $\begin{array}{r} -847.465\\ 367.993\\ 444.200\\ 517.678\\ 564.471\\ 647.455\\ 1055.016\\ 2136.185\\ 3375.131\end{array}$

T1 diagnostic: 0.04664996

 T_{2b} - T_{3b}

Si	-0.0670747137	-0.0691801973	-1.1675586565
Р	-0.0232691989	0.0376075294	1.0775722595

Н	1.3867569088	-0.0184094641	0.9258998757
Н	1.2047188839	-0.0646081678	-1.9307964510
Н	0.0213280371	1.2295534876	-0.1620733060

-1240.650 269.397 473.825 510.160 711.364 932.901 1638.483 2209.852 2405.228

T1 diagnostic: 0.02024202

T_{2a} - T_{3a}

Si	-0.0257841852	-0.0608539939	-1.1582883870
Р	-0.0300675983	0.0580600638	1.0698437518
Н	0.3281163090	-1.3004558846	1.2315102682
Η	0.3607957506	1.2115622437	-1.8217692409
Η	1.2290903432	-0.0341217194	-0.1101488796

Frequencies

-1052.019 376.657 468.472 495.805 799.182 1009.292 1656.753 2198.416 2429.637

T1 diagnostic: 0.02902485

S₂ - HSiP

P 0.86/8158505 -0.2516991123 -0.00012257	Р	0.8678158505	-0.2516991123	-0.0001225715
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Si	-1.1867516146	-0.6561963965	0.0000778149
Н	0.9711439536	1.6488223594	-0.3892226116
Н	0.9702041470	1.6486788257	0.3891818126
Н	-1.7161848667	0.7472746938	0.0000951256

-475.371 223.953 396.042 474.476 492.437 607.214 913.858 2143.008 3825.633

T1 diagnostic: 0.03715406

S₂ - HPSi

Р	-0.0004128464	-0.0291300843	-1.2084145297
Si	-0.0001845846	0.0877309349	0.9059917306
Н	-0.4079273329	1.6498635097	-1.4937158112
Н	0.4075105112	1.6497620700	-1.4939241625
Н	-0.0004774423	-1.4057324781	0.5212758698

Frequencies

-611.392 338.261 485.865 637.434 662.164 806.706 1371.016 1957.360 3328.625

S₂ - S₃

Si	-0.5404477827	-0.1968320542	-1.5587261521
Р	-0.3832726562	0.2129469565	0.5535561048
Н	0.3502128980	1.0189318187	-1.1393065493
Н	0.3582603164	-1.3849414039	-1.6661015339
Н	0.2134744445	-0.9630596572	1.0897651004

Frequencies

-1032.110 506.177 548.328 642.298 771.453 908.447 1842.297 2169.611 2375.443

T1 diagnostic: 0.03698734

T_{3a} - T_{3b}

Si	-0.0273397849	-0.3056984136	-1.2258086730
Р	0.0354469405	-0.7416397876	1.0353561771
Н	-1.4413433369	-0.3470881580	-1.6690017346
Н	0.5001599544	1.0441716457	-1.5340043830
Н	1.0134612793	0.2598554149	1.2443790261

Frequencies

-323.423
432.327
509.006
631.197
730.574
928.412
2219.802
2245.527
2428.618

 T_{3b} - HPSi

Si	0.1051473113	0.0056961911	-1.1720144869
Р	-0.0085922354	-0.0411628736	1.1005686201
Н	-1.3449023339	0.3950801246	-1.6200317725
Η	-1.3928986258	-0.5710479139	-0.9294457129
Н	-0.1894708433	1.3681064306	1.1281438187

Frequencies

-1452.023 246.527 384.815 422.616 548.614 805.211 1686.320 1855.414 2383.860

T1 diagnostic: 0.02033087

T_{3a} - HPSi

Si	-0.0984719308	0.0189529704	-1.1662709024
Р	0.0135000975	-0.0464395284	1.0980139048
Η	1.3957263462	0.5196178091	-0.7647620383
Η	1.3965943552	-0.3861236172	-1.4554352142
Η	-0.1649281569	1.3377712484	1.3325616421

Frequencies

-1413.407 221.464 416.058 458.541 561.465 819.024 1714.267 1861.564 2416.519

T_{3b} - HSiP

Si	0.3831457471	0.7854519969	0.1237675148
Р	-0.3725278044	-0.4796825338	1.8770570875
Н	0.2649141446	-0.2803845779	-0.9297619649
Н	1.2936919840	-0.3571002187	0.9335964695
Н	1.8948779287	0.3317153332	0.4653408929

Frequencies

-1513.298 380.179 505.342 677.625 862.817 949.204 1675.218 1855.239 2122.361

T1 diagnostic: 0.02740054

S₃ - HSiP

Si	0.2515551522	0.3133796636	0.2057124214
Р	-0.4377562872	-0.3197191671	1.9953493145
Н	0.2686455486	0.0027920609	-1.2411821701
Η	1.4748400260	-0.2847938359	1.0871343139
Н	1.9068175604	0.2883412782	0.4229861202

Frequencies

-1565.546 290.452 542.453 644.155 781.396 1031.392 1750.143 1907.974 2233.235 S₃ - HPSi

Si	-0.0002326329	-0.7093912084	-1.2592534446
Р	0.0003832199	0.1933494499	0.6366837223
Н	-0.0003993490	0.8579267541	-1.6203633758
Н	0.0003922983	-0.1248508856	-2.6409434942
Н	-0.0001435361	-1.0950096514	1.2384929028

Frequencies

-1077.145 336.816 371.988 578.052 658.036 843.802 1730.549 2169.100 2379.365

T1 diagnostic: 0.02154998

T_{3b} - T₄

Si	-0.0567137141	0.0004315182	-1.1209238398
Р	0.0004602713	-0.0009408228	1.1083091499
Η	-0.3559314285	1.2444437195	-1.8452818841
Η	-0.3502157270	-1.2439459669	-1.8469882699
Н	-1.2807896417	-0.0031407880	-0.0221753561

Frequencies

-1336.350 434.489 472.243 535.973 724.518 909.453 1633.425 2284.765 2315.076 T1 diagnostic: 0.02327160

T₄ - HSiP

Si	-0.6586660172	0.0534639733	-0.9312658011
Р	0.2551515316	-0.0695276704	1.0914110930
Н	0.8784699167	0.2315102379	-1.4510624018
Н	-0.6416174060	-1.2262326691	-1.6773856678
Н	0.1667443650	1.0101984582	-1.8089802422

Frequencies

-1284.797 312.418 454.774 504.818 772.671 972.836 1723.609 2057.062 2239.537

T1 diagnostic: 0.02097781

MSX

 MSX_1

Р	-0.0343198014	0.1525524625	-1.0338534459
Si	-0.0922627118	-0.2636508794	1.1066970529
Н	-1.0682879195	0.4278534880	-1.9701845395
Н	1.0444781295	0.4661776307	-1.9055342091
Н	-0.0076076968	-1.2650327018	-1.0587248584

Frequencies (Effective Hessian)

472.65 537.23 743.42 909.83 1203.02 2274.26 2287.80 2411.49

T1 diagnostic (singlet): 0.01900436 T1 diagnostic (triplet): 0.01772607

 MSX_2

Р	0.0176021892	-0.0668076713	-0.9134402743
Si	-0.0095163405	0.0291155029	1.1946887314
Н	0.5978586607	1.0588537656	-1.7393593119
Н	0.0584242972	-0.9239055193	-2.0355744280
Н	-0.5585688065	1.0404439221	-1.7698147174

Frequencies (Effective Hessian)

-115.89 441.69 552.66 971.60 1200.22 1918.74 1975.30 2364.12

T1 diagnostic (singlet): 0.02131358 T1 diagnostic (triplet): 0.01998028

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